**Product data sheet** 

# 1. General description

EEPP<sup>™</sup>- Efficiency Enhanced Pt Planar rectifier in a TO247-2L plastic package.

## 2. Features and benefits

- Fast switching
- · Reduces switching losses with improved lower reverse recovery charge
- Soft recovery characteristics
- Low thermal resistance
- · Low leakage current
- Planar termination structure
- High operating temperature capability (T<sub>i (max)</sub> = 175°C)
- Higher I<sub>FSM</sub> capability

## 3. Applications

- · Switched-Mode Power Supplies
- Power factor correction diode
- Uninterrupted Power Supply

### 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Va	lues		Unit
Absolute	maximum rating						
$V_{RRM}$	repetitive peak reverse voltage		1200		V		
$I_{F(AV)}$	average forward current	$δ = 0.5$ ; square-wave pulse; $T_{mb} \le 96$ °C; Fig. 1; Fig. 2; Fig. 3	40		А		
I <sub>FRM</sub>	repetitive peak forward current	$\delta$ = 0.5 ; t <sub>p</sub> = 25 μs; T <sub>mb</sub> ≤ 96 °C; square-wave pulse	80		А		
I <sub>FSM</sub>	non-repetitive peak forward current	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	300		А		
		$t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse;	330		Α		
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static ch	aracteristics						
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 40 A; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>		-	2.8	3.3	V
		I <sub>F</sub> = 40 A; T <sub>j</sub> = 150 °C; <u>Fig. 6</u>		-	2.2	-	V
Dynamic	characteristics						
t <sub>rr</sub>	reverse recovery time	$I_F = 1 \text{ A}$ ; $V_R = 30 \text{ V}$ ; $dI_F/dt = 100 \text{ A/}\mu\text{s}$ ; $T_j = 25 \text{ °C}$ ; Fig. 7		-	52	-	ns
Avalanch	e energy						
E <sub>AS</sub>	non-repetitive avalanche energy	T <sub>j(init)</sub> = 25 °C		30	-	-	mJ

# 5. Pinning information

#### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode	N°0°4	K — A 001aaa020
2	Α	anode	pοq	001aaa020
mb	mb	mounting base; connected to cathod	K A TO247-2L	

# 6. Ordering information

### **Table 3. Ordering information**

Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
BYC40W-1200P	TO247-2L	BYC40W-1200PQ	Tube	30	TO247A-2L	23-Jun-2017

## 7. Marking

#### Table 4. Marking codes

Type number	Marking codes
BYC40W-1200P	BYC40W-1200P

## 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
$V_{RRM}$	repetitive peak reverse voltage		1200	V
$V_{\text{RWM}}$	crest working reverse voltage		1200	V
$V_R$	reverse voltage	DC	1200	V
I <sub>F(AV)</sub>	average forward current	$δ = 0.5$ ; square-wave pulse; $T_{mb} \le 96$ °C; Fig. 1; Fig. 2; Fig. 3	40	А
I <sub>FRM</sub>	repetitive peak forward current	$δ = 0.5$ ; $t_p = 25 \mu s$ ; $T_{mb} \le 96 °C$ ; square-wave pulse	80	Α
I <sub>FSM</sub>	non-repetitive peak forward current	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	300	А
		$t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse;	330	А
T <sub>stg</sub>	storage temperature		-65 to 175	°C
T <sub>j</sub>	junction temperature		175	°C

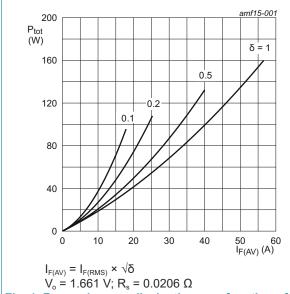
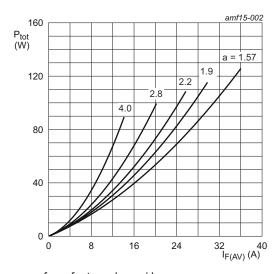
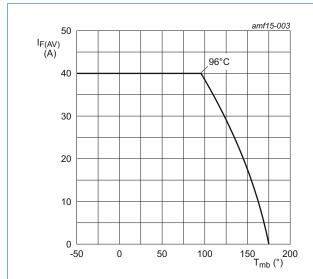


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



a = form factor =  $I_{F(RMS)}/I_{F(AV)}$ Vo = 1.661 V; Rs = 0.0206  $\Omega$ 

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values





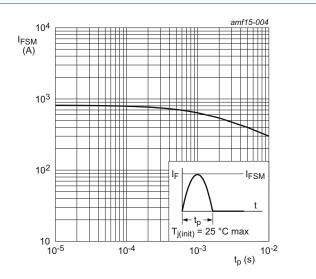
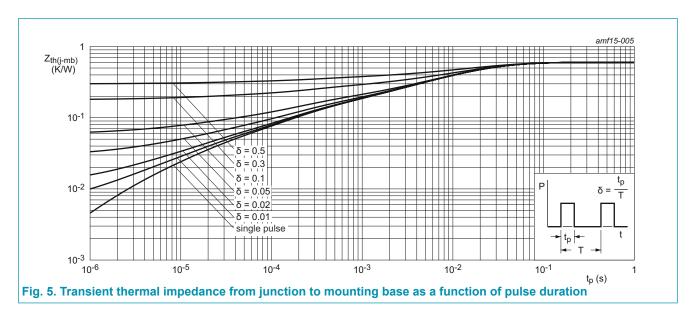


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values

## 9. Thermal characteristics

**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base	Fig. 5	-	-	0.6	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air	-	45	-	K/W

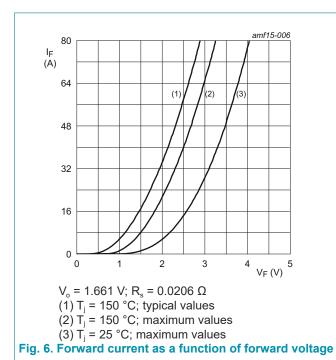


**Product data sheet** 

## 10. Characteristics

#### Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static ch	aracteristics					
V <sub>F</sub>	forward current	I <sub>F</sub> = 40 A; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>	-	2.8	3.3	V
		I <sub>F</sub> = 40 A; T <sub>j</sub> = 150 °C; <u>Fig. 6</u>	-	2.2	-	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 1200 V; T <sub>j</sub> = 25 °C	-	-	250	μΑ
		V <sub>R</sub> = 1200 V; T <sub>j</sub> = 150 °C	-	-	2	mA
Dynamic	characteristics					
$Q_r$	reverse charge	$I_F = 40 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$	-	863	-	nC
		$I_F = 40 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A}/\mu\text{s};$ $T_j = 125 \text{ °C}; Fig. 7$	-	2314	-	nC
		$I_F = 40 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_j = 150 \text{ °C}; Fig. 7$	-	2637	-	nC
t <sub>rr</sub>	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 100 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$	-	52	-	ns
		$I_F = 40 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$	-	91	-	ns
		$I_F = 40 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_j = 125 \text{ °C}; Fig. 7$	-	172	-	ns
		I <sub>F</sub> = 40 A; V <sub>R</sub> = 400 V; dI <sub>F</sub> /dt = 500 A/μs; T <sub>i</sub> = 150 °C; <u>Fig. 7</u>	-	186	-	ns
I <sub>RM</sub>	peak reverse recovery current	$I_F = 40 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$	-	19	-	А
		I <sub>F</sub> = 40 A; V <sub>R</sub> = 400 V; dI <sub>F</sub> /dt = 500 A/μs; T <sub>j</sub> = 125 °C; <u>Fig. 7</u>	-	27	-	А
		I <sub>F</sub> = 40 A; V <sub>R</sub> = 400 V; dI <sub>F</sub> /dt = 500 A/μs; T <sub>j</sub> = 150 °C; <u>Fig. 7</u>	-	28.4	-	А
Avalanci	ne energy					
E <sub>AS</sub>	non-repetitive avalanche energy	T <sub>j(init)</sub> = 25 °C	30	-	-	mJ



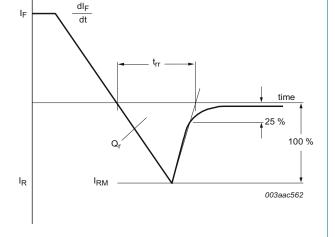
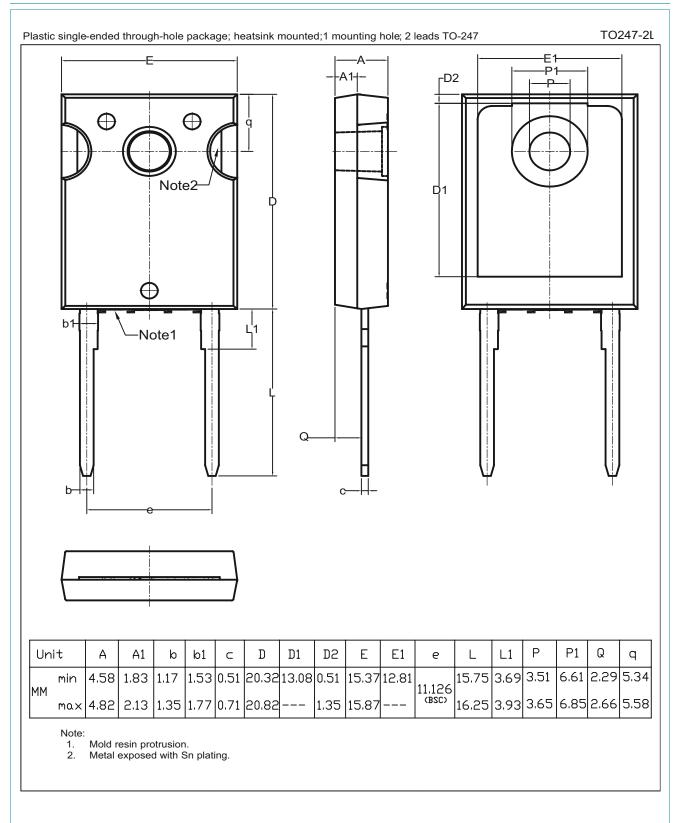


Fig. 7. Reverse recovery definitions; ramp recovery

## 11. Package outline



## 12. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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